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Semiconductor-Laser Physics

With 180 Figures



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CONTENTS

| | |
|--|------------|
| 1. Semiconductor Laser Diodes | 1 |
| 1-1. The Diode | 3 |
| 1-2. Basic Laser Device | 8 |
| 1-3. Heterostructures | 11 |
| 1-4. Gain and Index Guiding | 17 |
| 1-5. Semiconductor Microlasers | 21 |
| 1-6. Output Power-Current Characteristics | 23 |
| 1-7. Frequency Spectrum | 25 |
| 1-8. Transverse Mode Structure | 27 |
| 1-9. Phenomenological Gain Model | 29 |
| 2. Basic Concepts | 34 |
| 2-1. Elementary Aspects of Band Structures | 35 |
| 2-2. Units | 41 |
| 2-3. Fermi-Dirac Distributions | 42 |
| 2-4. Quantum Confinement | 49 |
| 2-5. Slowly-Varying Maxwell Equations | 55 |
| 2-6. Quantum Mechanics of the Semiconductor Medium | 59 |
| 3. Free-Carrier Theory | 71 |
| 3-1. Free-Carrier Equations of Motion | 72 |
| 3-2. Quasiequilibrium Approximation | 84 |
| 3-3. Semiconductor Gain | 93 |
| 3-4. Temperature Dependence of Gain | 102 |
| 3-5. Gain Saturation | 105 |
| 3-6. Carrier-Induced Refractive Index | 111 |
| 4. Coulomb Effects | 119 |
| 4-1. Many-Body Hamiltonian | 122 |
| 4-2. Plasma Screening | 124 |
| 4-3. Semiconductor Bloch Equations | 130 |
| 4-4. Bandgap Renormalization | 135 |
| 4-5. Interband Coulomb Effects | 136 |
| 4-6. Collision Processes | 142 |

| | |
|--|-----|
| 5. Many-Body Gain | 157 |
| 5-1. <i>Padé</i> Approximation | 158 |
| 5-2. Bulk Semiconductors | 160 |
| 5-3. Quantum Wells | 168 |
| | |
| 6. Band Mixing and Strain in Quantum Wells. | 178 |
| 6-1. Bloch Theorem | 179 |
| 6-2. Electronic States at $\mathbf{k} = 0$ | 180 |
| 6-3. $\mathbf{k} \cdot \mathbf{p}$ Theory | 184 |
| 6-4. Luttinger Hamiltonian | 189 |
| 6-5. Quantum Wells | 192 |
| 6-6. Strained Quantum Wells | 199 |
| 6-7. Bandstructure Calculation | 203 |
| 6-8. GaAs-AlGaAs Quantum Wells | 206 |
| 6-9. InGaAs-AlGaAs Strained Quantum Wells | 211 |
| 6-10. InGaAs-InP | 217 |
| 6-11. InGaP-InAlGaP | 224 |
| | |
| 7. Semiclassical Laser Theory | 232 |
| 7-1. Multimode Maxwell Equations | 233 |
| 7-2. Single-Mode Semiconductor Laser Theory | 238 |
| 7-3. Single-Mode Linear-Stability Analysis | 246 |
| 7-4. Injection Locking | 248 |
| 7-5. Coupled Resonators | 257 |
| 7-6. Laser Arrays | 268 |
| | |
| 8. Multimode Operation | 285 |
| 8-1. Multiwave Mixing | 286 |
| 8-2. Short-Cavity Sidemode Interactions | 295 |
| 8-3. Third-Order Multimode Equations | 306 |
| 8-4. Single-Mode Operation | 314 |
| 8-5. Two-Mode Operation | 317 |
| 8-6. Three-Mode Operation and Mode Locking | 323 |
| 8-7. Higher-Order Operation | 326 |

| | |
|--|------------|
| 9. Quantum Theory of the Laser | 329 |
| 9-1. Single-Mode Field Quantization | 329 |
| 9-2. Spontaneous Emission | 333 |
| 9-3. Quantum Langevin Equations | 337 |
| 9-4. Semiconductor Langevin Equations | 349 |
| 9-5. Power Spectra and Laser Linewidth | 354 |
| | |
| 10. Propagation Effects | 365 |
| 10-1. Longitudinal Field Dependence | 366 |
| 10-2. Lateral Field Distributions | 382 |
| 10-3. Diffraction Effects | 387 |
| 10-4. Filamentation in Amplifiers | 395 |
| 10-5. Unstable Resonator Lateral Mode Stability | 405 |
| | |
| 11. Beyond Quasiequilibrium Theory | 415 |
| 11-1. Nonequilibrium Laser Theory | 416 |
| 11-2. Numerical Results for VCSELs | 421 |
| 11-3. Pulse Propagation in Semiconductor Amplifiers | 431 |
| | |
| Appendix A: Two-Level Systems and Rate Equations | 438 |
| A-1. Two-Level Physics | 439 |
| A-2. Two-Level Laser Theory | 448 |
| | |
| Appendix B: $\mathbf{k} \cdot \mathbf{p}$ Theory | 456 |
| B-1. Nondegenerate Perturbation Theory | 456 |
| B-2. Degenerate Perturbation Theory | 459 |
| B-3. Luttinger Hamiltonian | 460 |
| | |
| Appendix C: Envelope Function Approach | 468 |
| C-1. Envelope Function Approximation | 468 |
| C-2. Dipole Matrix Elements | 474 |

| | |
|--|------------|
| Appendix D: Strain Effects | 479 |
| Appendix E: Some Langevin Goodies | 484 |
| Index | 491 |